

# PESD5V0X1BL

# Ultra low capacitance bidirectional ESD protection diode

Rev. 02 — 16 July 2009

**Product data sheet** 

### **Product profile**

#### 1.1 General description

Ultra low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a SOD882 leadless ultra small Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.

#### 1.2 Features

- Bidirectional ESD protection of one line ESD protection up to 9 kV
- Ultra low diode capacitance: C<sub>d</sub> = 0.9 pF IEC 61000-4-2; level 4 (ESD)
- Very low leakage current: I<sub>RM</sub> = 1 nA
   AEC-Q101 qualified

### 1.3 Applications

- USB interfaces
- Antenna protection
- 10/100/1000 Mbit/s Ethernet
- FireWire
- High-speed data lines
- Subscriber Identity Module (SIM) card protection
- Cellular handsets and accessories
- Portable electronics
- Communication systems
- Computers and peripherals
- Audio and video equipment

#### 1.4 Quick reference data

Table 1. Quick reference data

 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

| ame       | <u>'</u>                 |                        |     |     |     |      |
|-----------|--------------------------|------------------------|-----|-----|-----|------|
| Symbol    | Parameter                | Conditions             | Min | Тур | Max | Unit |
| Per diode | •                        |                        |     |     |     |      |
| $V_{RWM}$ | reverse standoff voltage |                        | -   | -   | 5   | V    |
| $C_d$     | diode capacitance        | $f = 1 MHz; V_R = 0 V$ | -   | 0.9 | 1.3 | pF   |



## 2. Pinning information

Table 2. Pinning

|     | •                 |                      |                  |
|-----|-------------------|----------------------|------------------|
| Pin | Description       | Simplified outline   | Graphic symbol   |
| 1   | cathode (diode 1) | [1]                  |                  |
| 2   | cathode (diode 2) | 1 2                  | 1 2<br>006aab041 |
|     |                   | Transparent top view |                  |

<sup>[1]</sup> The marking bar indicates pin 1.

## 3. Ordering information

Table 3. Ordering information

| Type number | Package | Package  |         |  |  |  |  |
|-------------|---------|--|---------|--|--|--|--|
|             | Name    | Description  | Version |  |  |  |  |
| PESD5V0X1BL | -       | leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.5$ mm | SOD882  |  |  |  |  |

## 4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PESD5V0X1BL | XX           |

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter            | Conditions | Min | Max  | Unit |
|------------------|----------------------|------------|-----|------|------|
| Per device       |                      |            |     |      |      |
| Tj               | junction temperature |            | -   | 150  | °C   |
| T <sub>amb</sub> | ambient temperature  |            | -55 | +150 | °C   |
| T <sub>stg</sub> | storage temperature  |            | -65 | +150 | °C   |

Table 6. ESD maximum ratings

 $T_{amb} = 25 \,^{\circ}C$  unless otherwise specified.

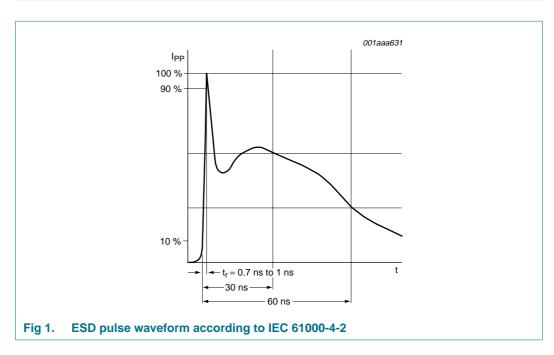
| anno             |                                 |                                      |       |      |     |      |
|------------------|---------------------------------|--------------------------------------|-------|------|-----|------|
| Symbol           | Parameter                       | Conditions                           | N     | /lin | Max | Unit |
| Per diode        |                                 |                                      |       |      |     |      |
| V <sub>ESD</sub> | electrostatic discharge voltage | IEC 61000-4-2<br>(contact discharge) | [1] - |      | 9   | kV   |
|                  |                                 | MIL-STD-883 (human body model)       | -     |      | 10  | kV   |

<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses.



Table 7. ESD standards compliance

| Standard                                | Conditions       |
|---|------------------|
| Per diode                               |                  |
| IEC 61000-4-2; level 4 (ESD)            | > 8 kV (contact) |
| MIL-STD-883; class 3 (human body model) | > 4 kV           |



## 6. Characteristics

Table 8. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified.

| Symbol           | Parameter                | Conditions           | Min | Тур | Max | Unit |
|------------------|--------------------------|----------------------|-----|-----|-----|------|
| Per diode        |                          |                      |     |     |     |      |
| $V_{RWM}$        | reverse standoff voltage |                      | -   | -   | 5   | V    |
| $I_{RM}$         | reverse leakage current  | $V_{RWM} = 5 V$      | -   | 1   | 100 | nA   |
| $V_{BR}$         | breakdown voltage        | $I_R = 5 \text{ mA}$ | 6.0 | 7.5 | 9.5 | V    |
| $C_d$            | diode capacitance        | f = 1 MHz            |     |     |     |      |
|                  |                          | $V_R = 0 V$          | -   | 0.9 | 1.3 | pF   |
|                  |                          | $V_R = 5 V$          | -   | 0.8 | 1.2 | pF   |
| r <sub>dif</sub> | differential resistance  | $I_R = 1 \text{ mA}$ | -   | -   | 100 | Ω    |

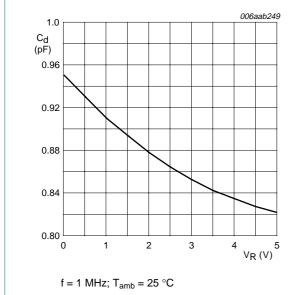


Fig 2. Diode capacitance as a function of reverse voltage; typical values

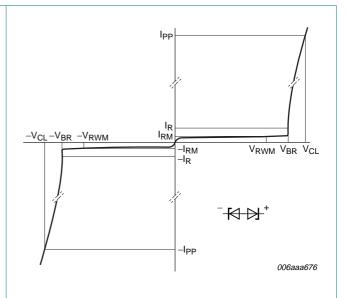
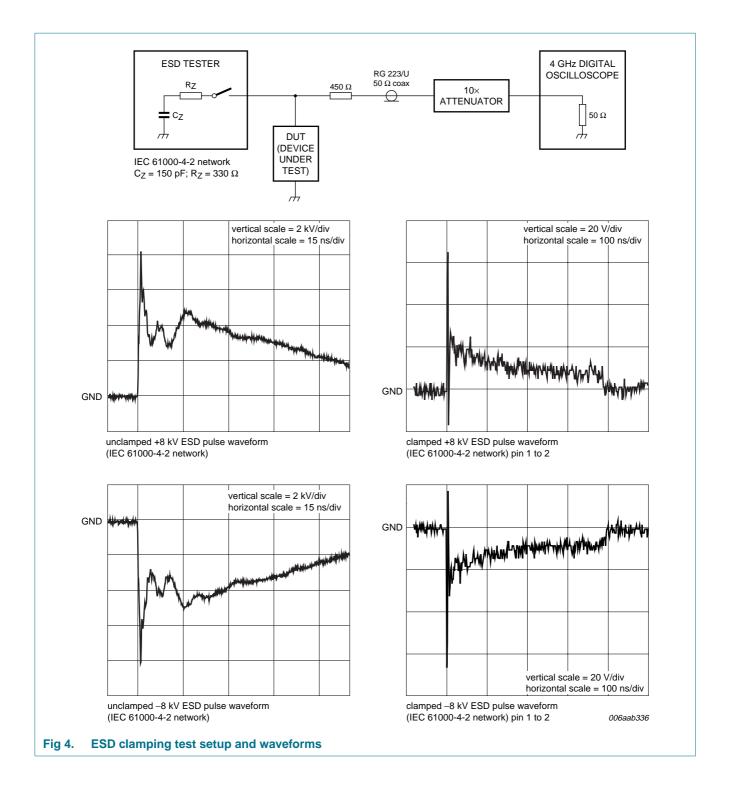


Fig 3. V-I characteristics for a bidirectional ESD protection diode

# PESD5V0X1BL

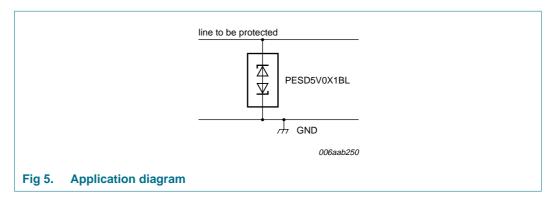
#### Ultra low capacitance bidirectional ESD protection diode



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## 7. Application information

PESD5V0X1BL is designed for the protection of one bidirectional data or signal line from the damage caused by ESD. The device may be used on lines where the signal polarities are both, positive and negative with respect to ground.



#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD and Electrical Fast Transient (EFT). The following guidelines are recommended:

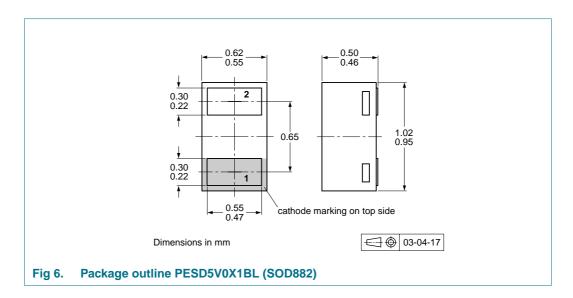
- 1. Place the device as close to the input terminal or connector as possible.
- 2. The path length between the device and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

#### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

## 9. Package outline



# 10. Packing information

Table 9. Packing methods

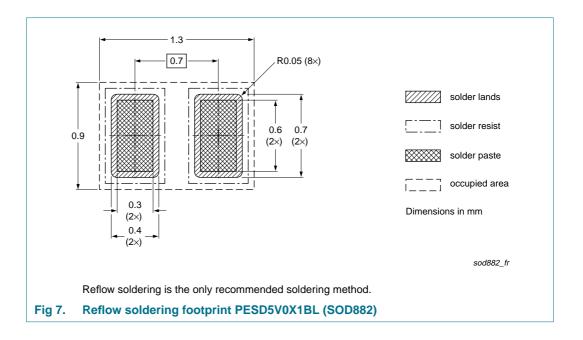
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description                    | Packing quantity |
|-------------|---------|--------------------------------|------------------|
|             |         |                                | 10000            |
| PESD5V0X1BL | SOD882  | 2 mm pitch, 8 mm tape and reel | -315             |

[1] For further information and the availability of packing methods, see <u>Section 14</u>.



## 11. Soldering





# 12. Revision history

### Table 10. Revision history

| Document ID                   | Release date                        | Data sheet status         | Change notice | Supersedes                    |
|-------------------------------|-------------------------------------|---------------------------|---------------|-------------------------------|
| PESD5V0X1BL_2                 | 20090716                            | Product data sheet        | -             | PESD5V0X1BA_<br>PESD5V0X1BL_1 |
| Modifications:                | <ul> <li>Type number P</li> </ul>   | ESD5V0X1BA removed        |               |                               |
|                               | <ul> <li>Figure 5: updat</li> </ul> | red                       |               |                               |
|                               | <ul> <li>Section 13 "Leg</li> </ul> | gal information": updated |               |                               |
| PESD5V0X1BA_<br>PESD5V0X1BL_1 | 20081104                            | Product data sheet        | -             | -                             |

### 13. Legal information

#### 13.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# PESD5V0X1BL

### Ultra low capacitance bidirectional ESD protection diode

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